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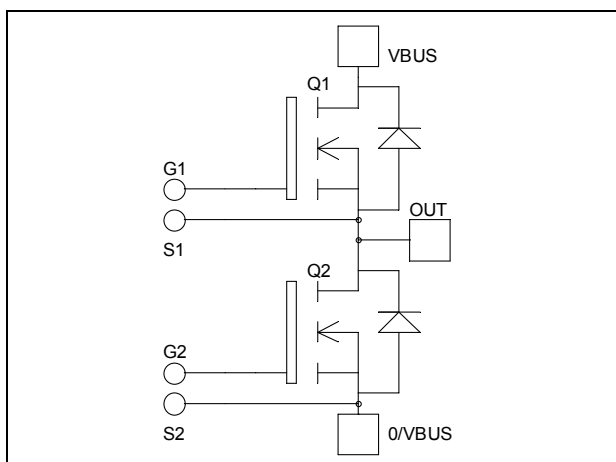
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## Phase leg MOSFET Power Module

 $V_{DSS} = 1200V$ 
 $R_{DSon} = 150m\Omega \text{ typ @ } T_j = 25^\circ C$ 
 $I_D = 60A \text{ @ } T_c = 25^\circ C$ 


### Application

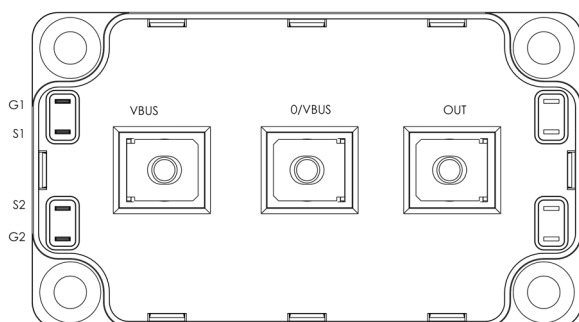
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Power MOS 7<sup>®</sup> FREDFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



### Absolute maximum ratings

| Symbol     | Parameter   | Max ratings  | Unit       |
|------------|---|--|------------|
| $V_{DSS}$  | Drain - Source Breakdown Voltage                  | 1200   | V          |
| $I_D$      | Continuous Drain Current                          | $T_c = 25^\circ C$<br>60<br>$T_c = 80^\circ C$<br>45 | A          |
| $I_{DM}$   | Pulsed Drain current                              | 240  |            |
| $V_{GS}$   | Gate - Source Voltage                             | $\pm 30$   | V          |
| $R_{DSon}$ | Drain - Source ON Resistance                      | 175  | m $\Omega$ |
| $P_D$      | Maximum Power Dissipation                         | $T_c = 25^\circ C$<br>1250                           | W          |
| $I_{AR}$   | Avalanche current (repetitive and non repetitive) | 22   | A          |
| $E_{AR}$   | Repetitive Avalanche Energy                       | 50   | mJ         |
| $E_{AS}$   | Single Pulse Avalanche Energy                     | 3000   |            |

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

### Electrical Characteristics

| Symbol       | Characteristic                  | Test Conditions  | Min | Typ | Max       | Unit          |
|--------------|---------------------------------|--|-----|-----|-----------|---------------|
| $I_{DSS}$    | Zero Gate Voltage Drain Current | $V_{GS} = 0V, V_{DS} = 1200V$<br>$T_j = 25^\circ\text{C}$  |     |     | 500       | $\mu\text{A}$ |
|              |                                 | $V_{GS} = 0V, V_{DS} = 1000V$<br>$T_j = 125^\circ\text{C}$ |     |     | 3000      |               |
| $R_{DS(on)}$ | Drain – Source on Resistance    | $V_{GS} = 10V, I_D = 30A$                                  |     | 150 | 175       | $m\Omega$     |
| $V_{GS(th)}$ | Gate Threshold Voltage          | $V_{GS} = V_{DS}, I_D = 10mA$                              | 3   |     | 5         | V             |
| $I_{GSS}$    | Gate – Source Leakage Current   | $V_{GS} = \pm 30V, V_{DS} = 0V$                            |     |     | $\pm 250$ | nA            |

### Dynamic Characteristics

| Symbol       | Characteristic               | Test Conditions   | Min | Typ  | Max | Unit |
|--------------|------------------------------|---|-----|------|-----|------|
| $C_{iss}$    | Input Capacitance            | $V_{GS} = 0V$<br>$V_{DS} = 25V$<br>$f = 1MHz$   |     | 20.6 |     | nF   |
| $C_{oss}$    | Output Capacitance           |   |     | 3.08 |     |      |
| $C_{rss}$    | Reverse Transfer Capacitance |   |     | 0.52 |     |      |
| $Q_g$        | Total gate Charge            | $V_{GS} = 10V$<br>$V_{Bus} = 600V$<br>$I_D = 60A$   |     | 748  |     | nC   |
| $Q_{gs}$     | Gate – Source Charge         |   |     | 96   |     |      |
| $Q_{gd}$     | Gate – Drain Charge          |   |     | 480  |     |      |
| $T_{d(on)}$  | Turn-on Delay Time           | <b>Inductive switching @ <math>125^\circ\text{C}</math></b><br>$V_{GS} = 15V$<br>$V_{Bus} = 800V$<br>$I_D = 60A$<br>$R_G = 1.2\Omega$ |     | 20   |     | ns   |
| $T_r$        | Rise Time                    |   |     | 15   |     |      |
| $T_{d(off)}$ | Turn-off Delay Time          |   |     | 160  |     |      |
| $T_f$        | Fall Time                    |   |     | 45   |     |      |
| $E_{on}$     | Turn-on Switching Energy     | <b>Inductive switching @ <math>25^\circ\text{C}</math></b><br>$V_{GS} = 15V, V_{Bus} = 800V$<br>$I_D = 60A, R_G = 1.2\Omega$          |     | 3.96 |     | mJ   |
| $E_{off}$    | Turn-off Switching Energy    |   |     | 2.74 |     |      |
| $E_{on}$     | Turn-on Switching Energy     | <b>Inductive switching @ <math>125^\circ\text{C}</math></b><br>$V_{GS} = 15V, V_{Bus} = 800V$<br>$I_D = 60A, R_G = 1.2\Omega$         |     | 6.26 |     | mJ   |
| $E_{off}$    | Turn-off Switching Energy    |   |     | 3.43 |     |      |

### Source - Drain diode ratings and characteristics

| Symbol          | Characteristic                            | Test Conditions  |                        | Min | Typ | Max | Unit |
|-----------------|---|--|------------------------|-----|-----|-----|------|
| I <sub>S</sub>  | Continuous Source current<br>(Body diode) |  | T <sub>C</sub> = 25°C  |     |     | 60  | A    |
|                 |   |  | T <sub>C</sub> = 80°C  |     |     | 45  |      |
| V <sub>SD</sub> | Diode Forward Voltage                     | V <sub>GS</sub> = 0V, I <sub>S</sub> = - 60A                                     |                        |     |     | 1.3 | V    |
| dv/dt           | Peak Diode Recovery ❶                     |  |                        |     |     | 18  | V/ns |
| t <sub>rr</sub> | Reverse Recovery Time                     | I <sub>S</sub> = - 60A<br>V <sub>R</sub> = 600V<br>di <sub>S</sub> /dt = 400A/μs | T <sub>j</sub> = 25°C  |     |     | 320 | ns   |
|                 |   |  | T <sub>j</sub> = 125°C |     |     | 650 |      |
| Q <sub>rr</sub> | Reverse Recovery Charge                   |  | T <sub>j</sub> = 25°C  |     | 8   |     | μC   |
|                 |   |  | T <sub>i</sub> = 125°C |     | 28  |     |      |

❶  $dv/dt$  numbers reflect the limitations of the circuit rather than the device itself.

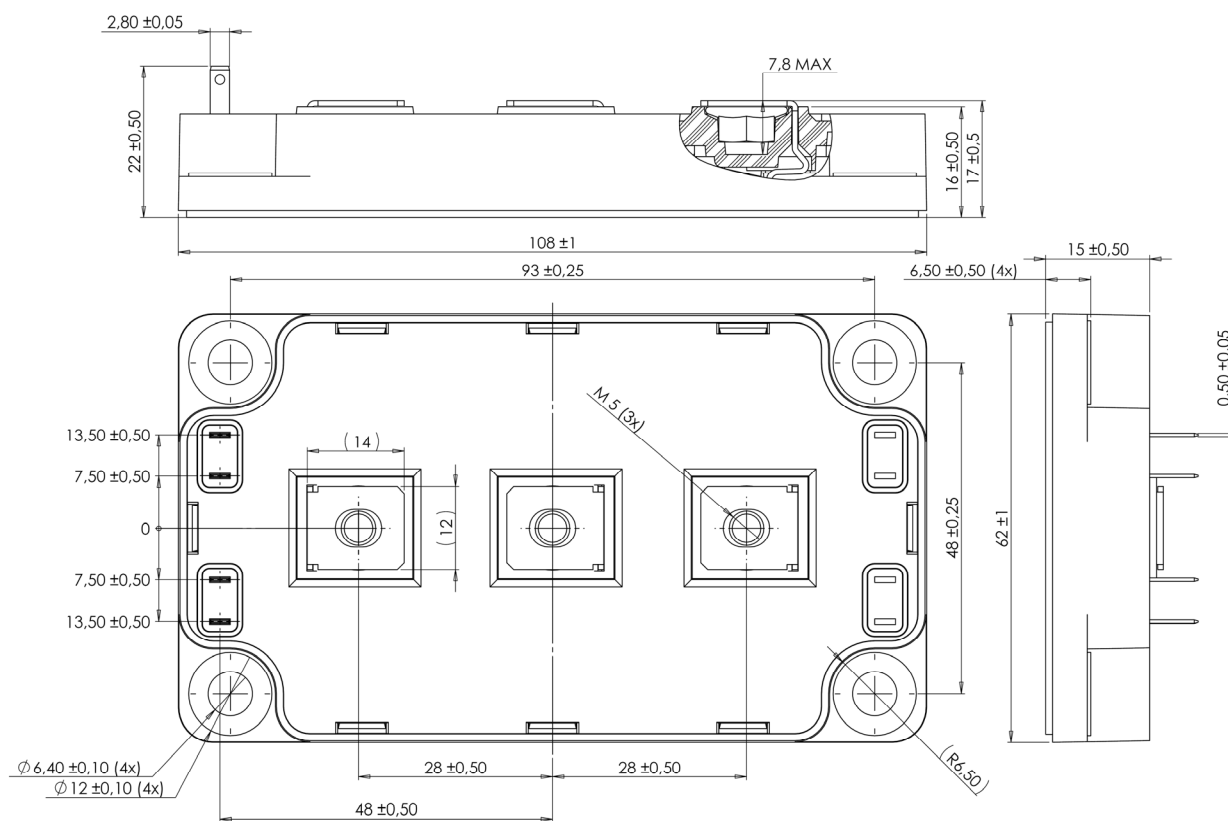
$I_S \leq -60A$      $di/dt \leq 700A/\mu s$      $V_R \leq V_{DSS}$      $T_j \leq 150^\circ\text{C}$



## Thermal and package characteristics

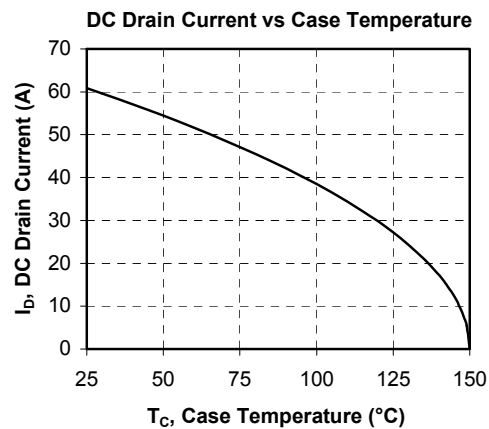
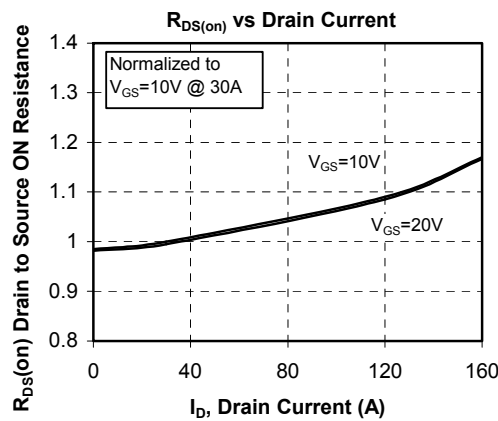
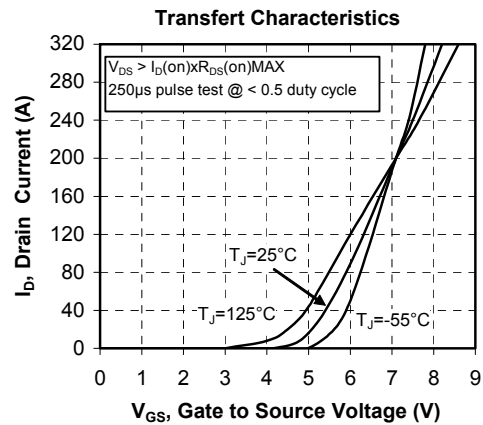
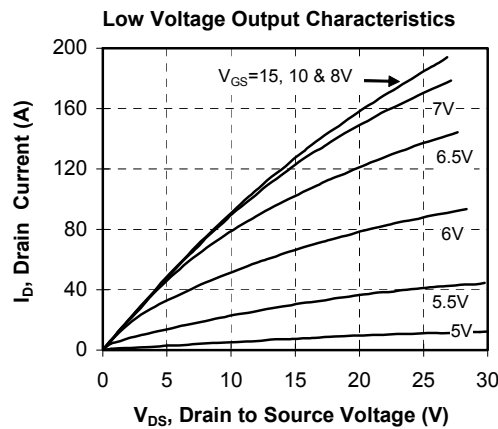
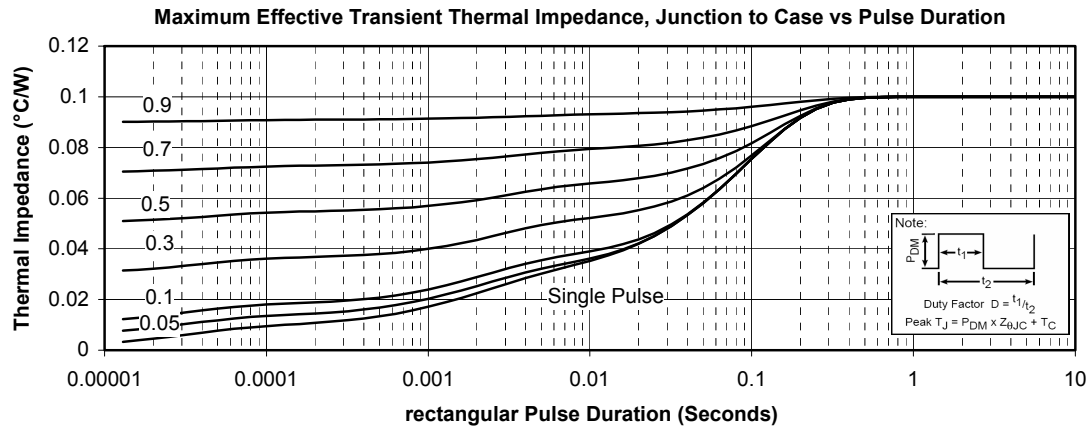
| Symbol            | Characteristic  | Min           | Typ | Max | Unit |
|-------------------|---|---------------|-----|-----|------|
| R <sub>thJC</sub> | Junction to Case Thermal Resistance                           |               |     | 0.1 | °C/W |
| V <sub>ISOL</sub> | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | 4000          |     |     | V    |
| T <sub>J</sub>    | Operating junction temperature range                          | -40           |     | 150 | °C   |
| T <sub>STG</sub>  | Storage Temperature Range                                     | -40           |     | 125 |      |
| T <sub>C</sub>    | Operating Case Temperature                                    | -40           |     | 100 |      |
| Torque            | Mounting torque   | To heatsink   | M6  | 3   | N.m  |
|                   |   | For terminals | M5  | 2   |      |
| Wt                | Package Weight  |               |     | 300 | g    |

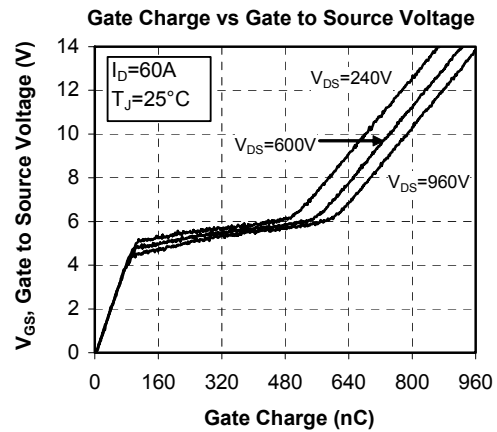
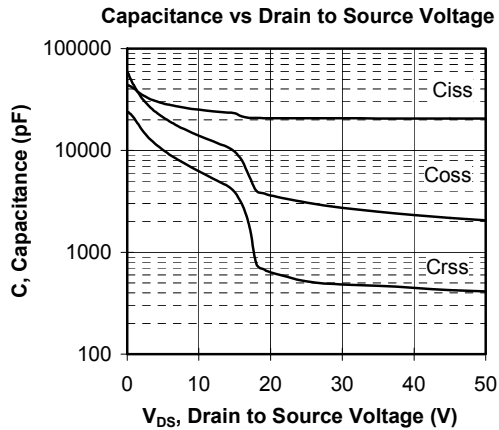
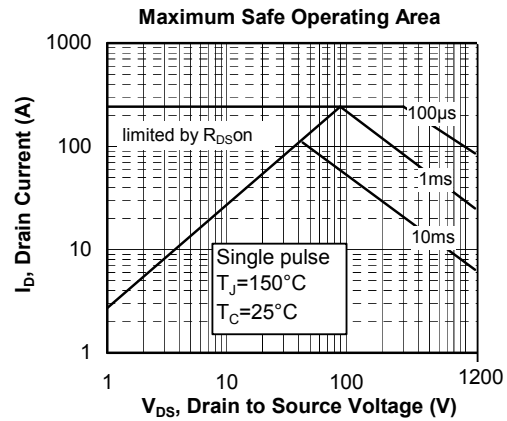
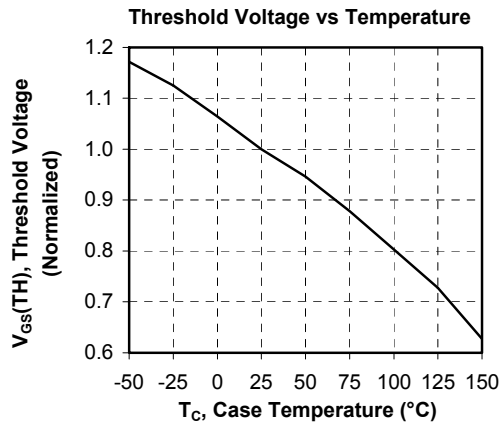
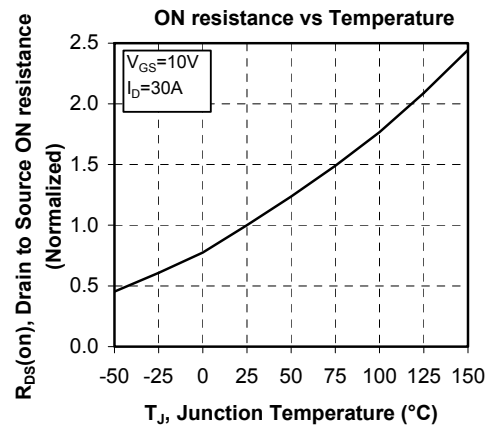
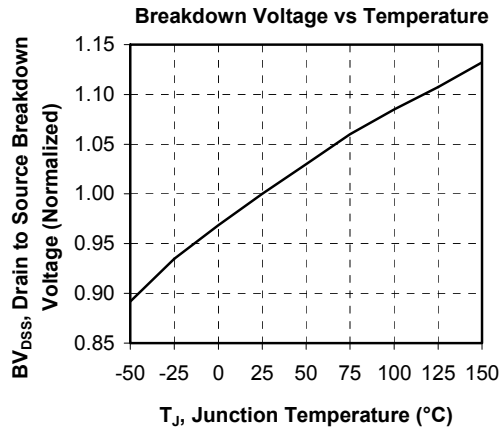
### SP6 Package outline (dimensions in mm)

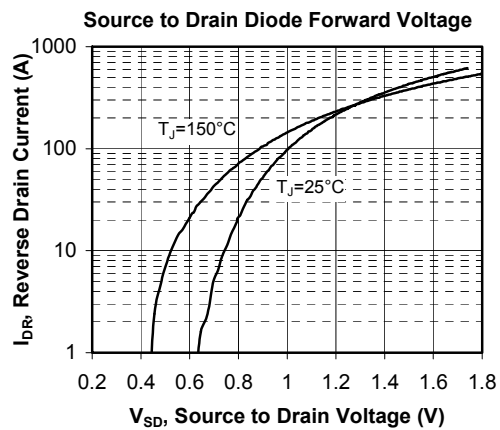
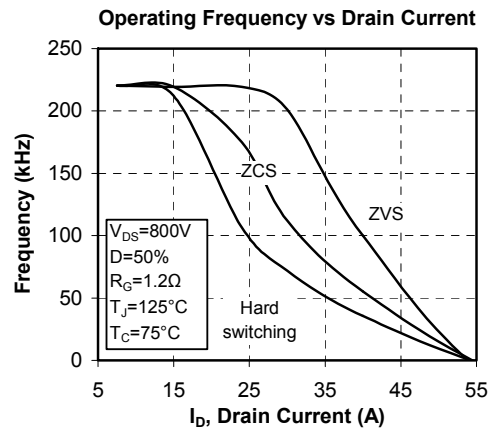
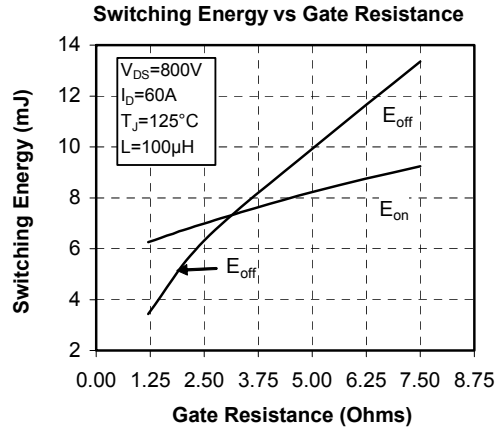
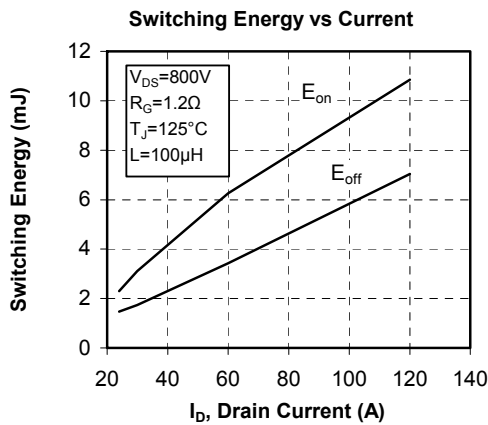
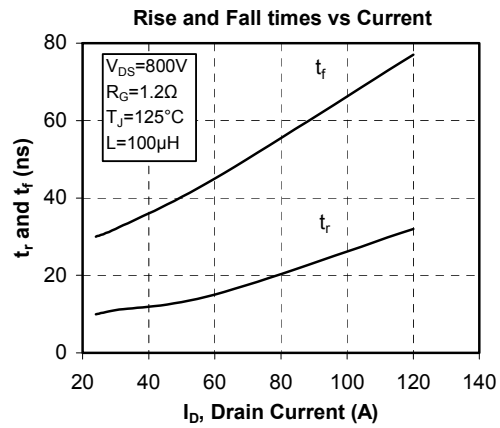
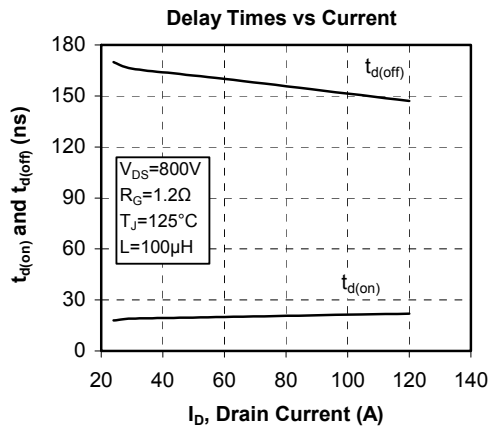


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

## Typical Performance Curve







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